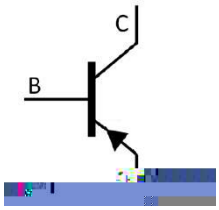
SOT-89 PNP Silicon PNP transistor in a SOT-89 Plastic Package.

, , 2SC2881

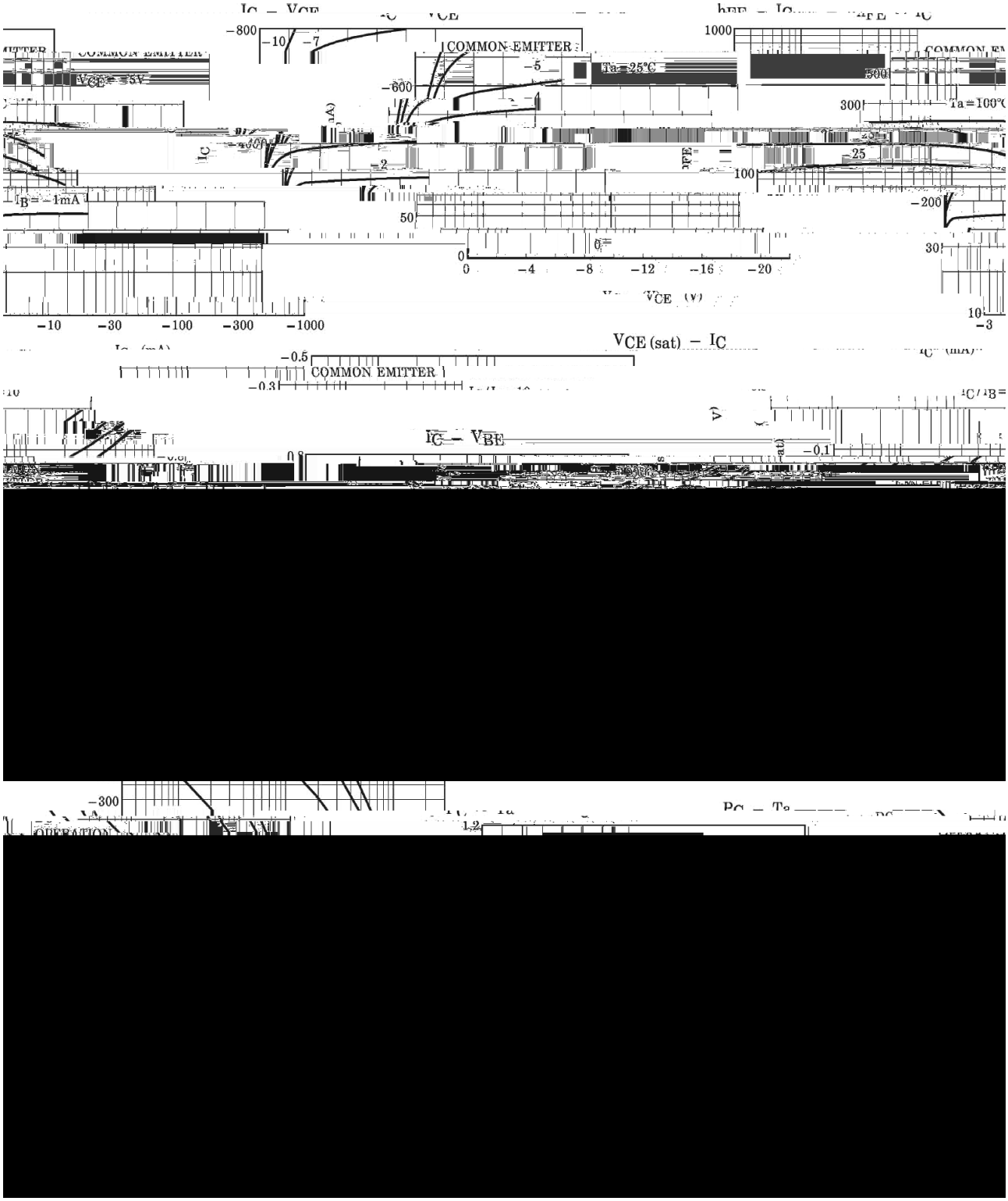
High f_T, high V_{CEO}, small flat package, complementary pair with 2SC2881.

Power amplifier applications.

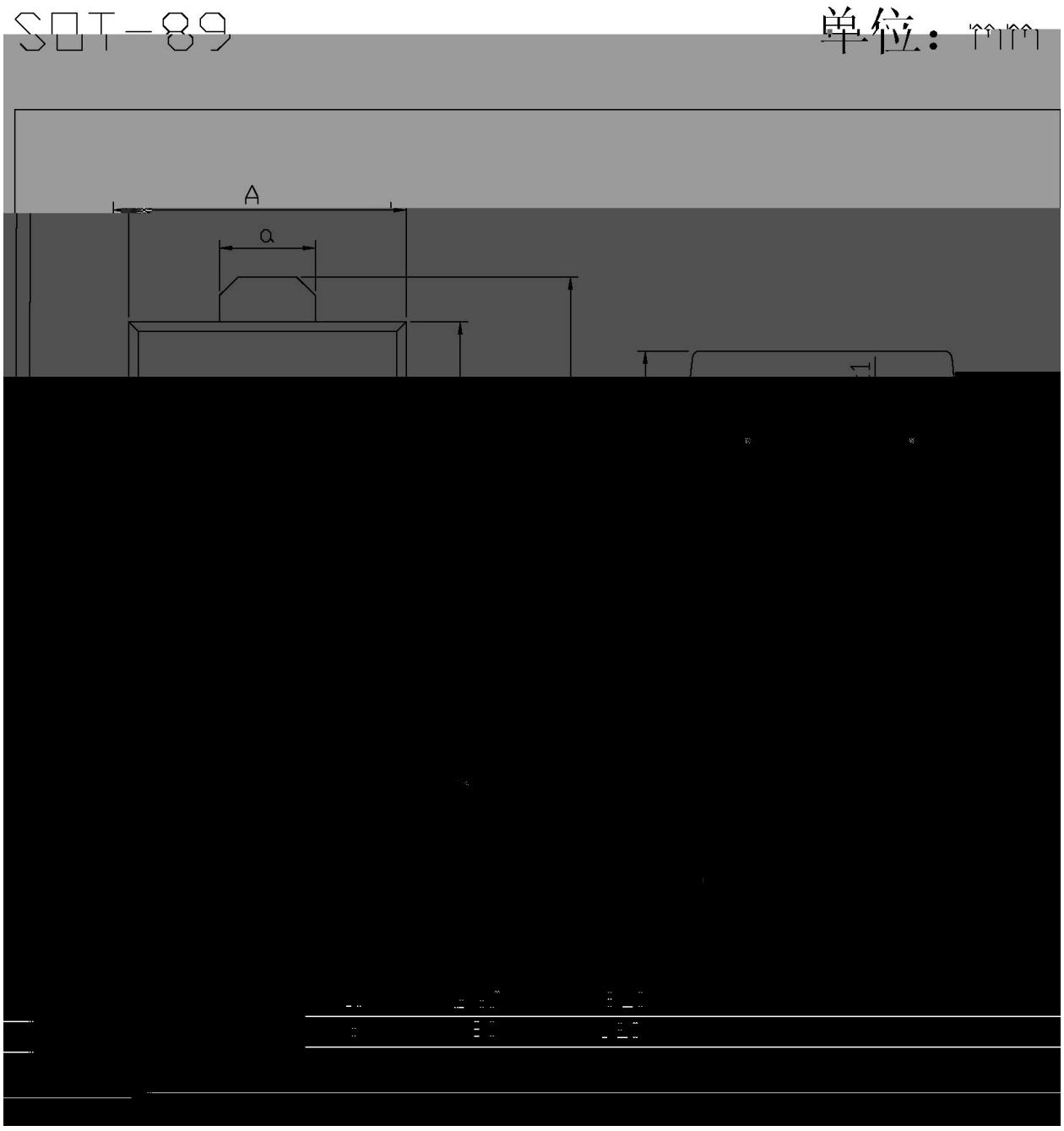


Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-120	V
Collector to Emitter Voltage	V_{CEO}	-120	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current-Continuous	I_C	-800	mA
Collector Base-Continuous	I_B	-160	mA
Collector Power Dissipation	P_C	500	mW
Collector Power Dissipation*	$*P_C$	1.0	W
Junction Temperature	T_j	150	

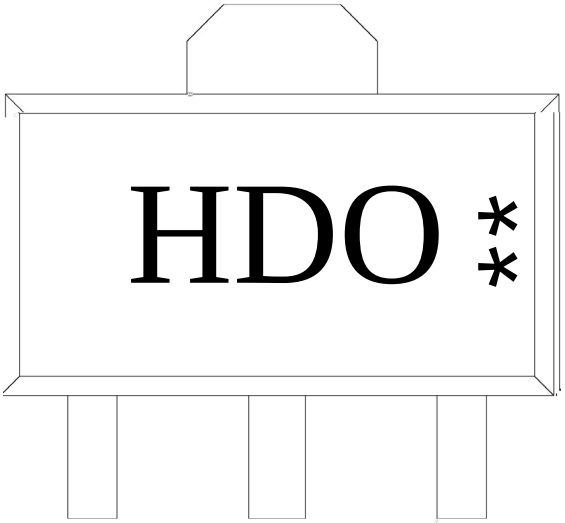
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



H

D

O h_{FE}

**

Note:

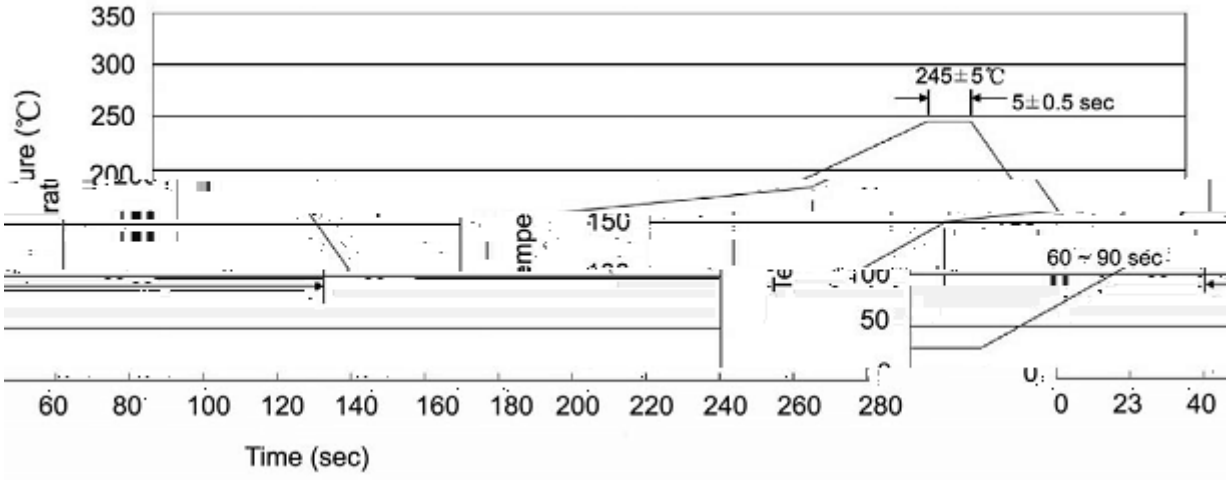
H: Company Code.

D: Product Type.

O: h_{FE} Classifications Symbol

**: Lot No. Code, code change with Lot No.

( ) /



Note:

1	25	150	60	90sec;	1.Preheating:25~150 , Time:60~90sec.
2	245±5			5±0.5sec;	2.Peak Temp.:245±5 , Duration:5±0.5sec.
3		2	10	/sec.	3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5	10±1 sec.	Temp.:260±5	Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension		(unit mm^3)
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box	Outer Box
SOT-89	1,000	7	7,000	8	56,000	7 ×12	180×120×180	385×257×392